

SCHOTTKY BARRIER RECTIFIERS

REVERSE VOLTAGE - **70 to 100** Volts
FORWARD CURRENT - **16** Amperes

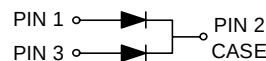
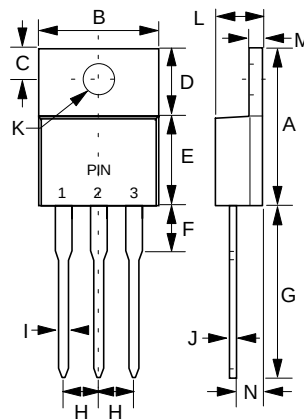
FEATURES

- Metal of silicon rectifier, majority carrier conduction
- Guard ring for transient protection
- Low power loss, high efficiency
- High current capability, low VF
- High surge capacity
- Plastic package has UL flammability classification 94V-0
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case : TO-220AB molded plastic
- Polarity : As marked on the body
- Weight : 0.08 ounces, 2.24 grams
- Mounting position : Any

TO-220AB



TO-220AB		
DIM.	MIN.	MAX.
A	14.22	15.88
B	9.65	10.67
C	2.54	3.43
D	5.84	6.86
E	8.26	9.28
F	-	6.35
G	12.70	14.73
H	2.29	2.79
I	0.51	1.14
J	0.30	0.64
K	3.53 $\varnothing$	4.09 $\varnothing$
L	3.56	4.83
M	1.14	1.40
N	2.03	2.92

All Dimensions in millimeter

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	MBR1670CT	MBR1680CT	MBR1690CT	MBR16100CT	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	70	80	90	100	V
Maximum RMS Voltage	V _{RMS}	49	56	63	70	V
Maximum DC Blocking Voltage	V _{DC}	70	80	90	100	V
Maximum Average Forward Rectified Current at TC=100°C (See Fig.1)	I <sub(av)< sub=""></sub(av)<>	16				A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC METHOD)	I _{FSM}	125				A
Voltage Rate of Change (Rated VR)	dv/dt	10000				V/us
Maximum Forward Voltage, (Note 1)	V _F	@I _F =8A T _J =25°C 0.85 @I _F =8A T _J =125°C 0.75 @I _F =16A T _J =25°C 0.95 @I _F =16A T _J =125°C 0.85				V
Maximum DC Reverse Current at Rated DC Blocking Voltage	I _R	@T _J =25°C 0.1 @T _J =125°C 100				mA
Typical Junction Capacitance, per element (Note 2)	C _J	275				pF
Typical Thermal Resistance (Note 3)	R _{θJC}	2.0				°C/W
Operating Temperature Range	T _J	-55 to +150				°C
Storage Temperature Range	T _{STG}	-55 to +175				°C

NOTES : 1. 300us Pulse Width, 2% Duty Cycle.
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
3. Thermal Resistance Junction to Case.

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